



Amendments to the Claims

This is to inform you that the claims will replace all prior versions and listings of claims in the application.

Listing of Claims:

1. (currently amended): An organic electro-luminescent display device, comprising:
  - a glass substrate;
  - an optic-compensation film of transparent dielectric material formed on the surface of the glass substrate;
  - an anode layer formed directly on the optic-compensation film;
  - a laminated body of organic material formed on the anode layer; and
  - a cathode layer formed on the laminated body.
2. (original): The organic electro-luminescent display device as claimed in claim 1, wherein the optic-compensation film is silicon nitride (SiNx).
3. (original): The organic electro-luminescent display device as claimed in claim 1, wherein the optic-compensation film is of 100~3000Å thickness.
4. (original): The organic electro-luminescent display device as claimed in claim 1, wherein the optic-compensation film promotes transparency of red light to approximately 90%.
5. (original): The organic electro-luminescent display device as claimed in claim 1, wherein the anode layer is ITO.
6. (original): The organic electro-luminescent display device as claimed in claim 1, wherein the laminated body comprises:
  - a hole-injecting layer formed on the anode layer;
  - an organic luminescent material layer formed on the hole-injecting layer; and

an electron-injecting layer formed on the organic luminescent material layer.

7. (original): The organic electro-luminescent display device as claimed in claim 1, wherein the organic electro-luminescent display device is an OLED device or a PLED device.

8. (currently amended): A method of forming an organic electro-luminescent display device, comprising:

providing a glass substrate;

forming an optic-compensation film of transparent dielectric material on the surface of the glass substrate, in which the transparent nature of the optic-compensation film is not limited to light of a specific wavelength;

forming an anode layer directly on the optic-compensation film;

forming a laminated body of organic material on the anode layer; and

forming a cathode layer on the laminated body.

9. (original): The method of forming an organic electro-luminescent display device as claimed in claim 8, wherein the optic-compensation film is silicon nitride (SiNx).

10. (original): The method of forming an organic electro-luminescent display device as claimed in claim 8, wherein the optic-compensation film is of 100~3000Å thickness.

11. (original): The method of forming an organic electro-luminescent display device as claimed in claim 8, wherein the optic-compensation film promotes transparency of red light to approximately 90%.

12. (original): The method of forming an organic electro-luminescent display device as claimed in claim 8, wherein the optic-compensation film increases the transparency of red light.

13. (original): The method of forming an organic electro-luminescent display device as claimed in claim 8, wherein the anode layer is ITO.

14. (original): The method of forming an organic electro-luminescent display device as claimed in claim 8, wherein the laminated body comprises:

- a hole-injecting layer formed on the anode layer;
- an organic luminescent material layer formed on the hole-injecting layer; and
- an electron-injecting layer formed on the organic luminescent material layer.

15. (original): The method of forming an organic electro-luminescent display device as claimed in claim 8, wherein the organic electro-luminescent display device is an OLED device or a PLED device.